

2. (Amended) The magnetoresistance effect element as set forth in claim 1, wherein said electrodes comprise at least one selected from the group consisting of Cu, Ag, Au, [A1] Al and alloys thereof.

11. (Amended) A magnetoresistance effect element comprising:  
a spin valve film having a first ferromagnetic layer, a nonmagnetic layer, a  
second ferromagnetic layer, and an antiferromagnetic layer, wherein the nonmagnetic  
layer is provided between the first and second ferromagnetic layers, and the  
antiferromagnetic layer is provided on the first or second ferromagnetic layer, the  
antiferromagnetic layer comprising an alloy of PtMn.

#### REMARKS

Entry of the above-captioned amendments is requested prior to examination of the application on the merits. After entry of this preliminary amendment, the status of the claims is as follows: patented claims 1-10 are pending, added claims 21, 24, 25, and 30-37 are canceled, and added claims 11-20, 22, 23, 26-29, and 38 are pending.

Respectfully submitted,

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